

Description

- The Super Bright Green source color devices are made with Gallium Phosphide Green Light Emitting Diode

1. All dimensions are in millimeters (inches), Tolerance is $\pm 0.25(0.01")$ unless otherwise noted.
2. Specifications are subject to change without notice.

Selection Guide

Part No.	Dice	Lens Type	Iv (ucd) @ 10 mA		Description
			Min.	Typ.	
KPSA02-102	SUPER BRIGHT GREEN (GaP)	WHITE DIFFUSED	1900	10000	Common Anode,Rt.Hand Decimal

Electrical / Optical Characteristics at T_A=25°C

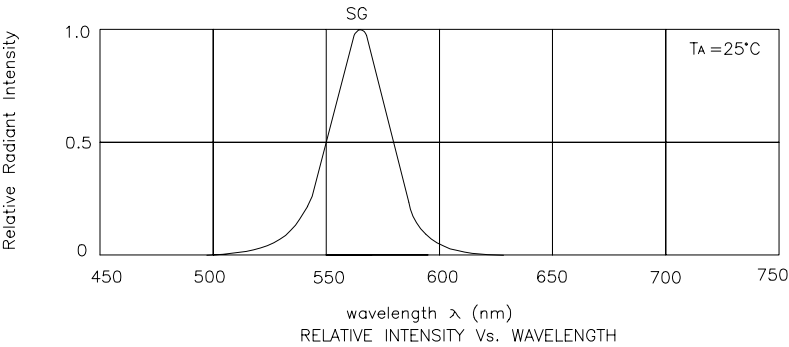
Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ_{peak}	Peak Wavelength	Super Bright Green	565		nm	I _F =20mA
λ_D	Dominate Wavelength	Super Bright Green	568		nm	I _F =20mA
$\Delta\lambda_{1/2}$	Spectral Line Half-width	Super Bright Green	30		nm	I _F =20mA
C	Capacitance	Super Bright Green	15		pF	V _F =0V;f=1MHz
V _F	Forward Voltage	Super Bright Green	2.2	2.5	V	I _F =20mA
I _R	Reverse Current	Super Bright Green		10	uA	V _R = 5V

Absolute Maximum Ratings at T_A=25°C

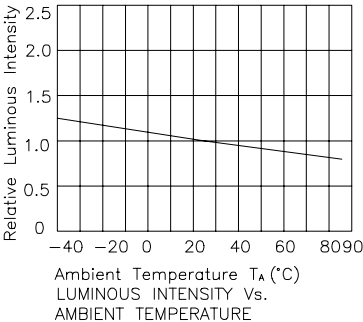
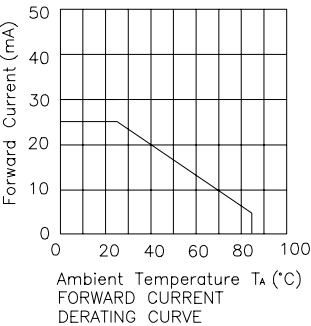
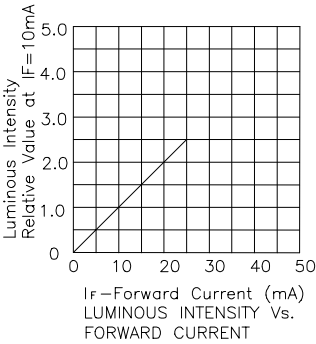
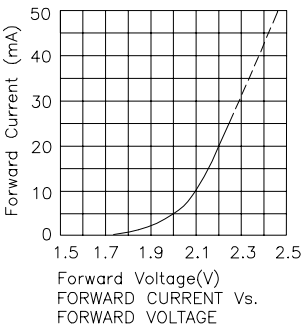
Parameter	Super Bright Green	Units
Power dissipation	105	mW
DC Forward Current	25	mA
Peak Forward Current [1]	140	mA
Reverse Voltage	5	V
Operating/Storage Temperature	-40°C To +85°C	

Note:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.



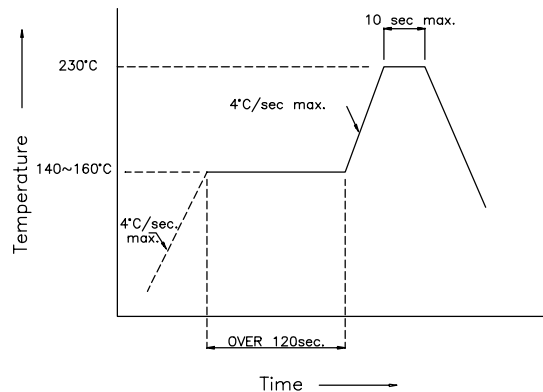
Super Bright Green KPSA02-102



KPSA02-102

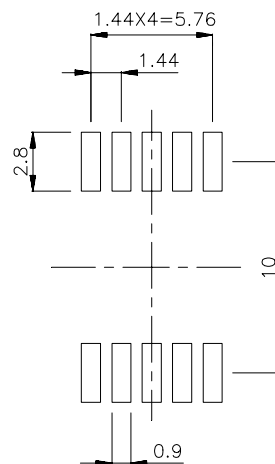
SMT Reflow Soldering Instruction

Number of reflow process shall be less than 2 times and cooling process to normal temperature is required between first and second soldering process.



Recommended Soldering Pattern

(Units : mm)



Tape Specification

(Units : mm)

